

INTROPUCTION

AN1882 APPLICATION NOTE

DESIGNING WITH L6926, HIGH EFFICIENCY MONOLITHIC SYNCHRONOUS STEP DOWN REGULATOR

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This application note details the main features and application advantages of this new synchronous step down regulator. After describing how the device works and the main features, a stepby-step design section is provided in order to help the selection of the external components and the evaluation of the losses. The device performances are shown in terms of efficiency and thermal results. At the end, some application ideas are proposed.

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1 INTRODUCTION

This new product, realized in BCDV technology, is a high efficiency monolithic synchronous step down regulator capable to deliver up to 800mA of continuous output current and to regulate the output voltage from 0.6V up to V_{IN} thanks to the 100% duty cycle operation capability. The input voltage ranges fro 2V to 5.5V. The control loop architecture is based on a constant frequency peak current mode, while high efficiency at light loads is achieved by low consumption functionality. The very low quiescent current (25μ A) and shutdown current (0.2μ A) make the device very suitable to supply battery-powered equipment like PDA's and hand held terminals, DSC's (digital still cameras) cellular phones. The switching frequency is internally set at 600 KHz but the device can be externally synchronized up to 1.4MHz. An internal reference voltage of 0.6V (typ), allows the device to regulate minimum output voltage of the same low value. The low MOSFETs RDSON ensures high efficiency at high output current. Additional interesting features are: hysteretic UVLO, OVP, constant current short circuit protection, PGOOD and thermal shutdown. The MSOP8 package allows a significant board space saving.

Figure 1. Application test circuit



Figure 2. Application board



Figure 3. Pins connection



Figure 4. MSOP8 package



2 PINS FUNCTION

Table 1. Pin description

N.	Name	Description
1	RUN	Shutdown input. When connected to a lower voltage than 0.5V (down to GND) the device stops working. When connected to a higher voltage than 1.3V (up to V_{CC}) the device is enabled. The pin must not be left floating.
2	COMP	Error amplifier output. A compensation network has to be connected from this pin to GND. Usually a 220pF capacitor is enough to guarantee the loop stability (see related section).
3	VFB	Error amplifier inverting input, used to adjust the output voltage (from 0.6V to V_{IN}) by an external divider.
4	GND	Ground.
5	LX	Switchs output node. Common point between high side and low side MOSFETs
6	Vcc	Input voltage. The operating input voltage range is from 2V to 5.5V. An internal UVLO circuit realizes a 200mV (typ) hysteresis.
7	SYNC	Operating mode selector input. Low Consumption Mode, when connected to a higher voltage than 1.3V (up to V_{CC}). Low Noise Mode when connected to a lower than 0.5V (down to GND). Synchronization mode when connected to an external appropriate clock generator. This pin must not be left floating.
8	PGOOD	Power good comparator output. It is an open drain output. A pull-up resistor should be connected between PGOOD and V_O . The pin is forced low when the output voltage is lower than 90% of the regulated output voltage and goes high when the output voltage is greater than 90% of the regulated output voltage. If not used, the pin can be left floating.

3 BLOCK DIAGRAM

Figure 5. Block diagram

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4 FUNCTIONAL DESCRIPTION

The main loop uses constant frequency peak current mode architecture. Each cycle, the high side MOS-FET is turned on, triggered by the oscillator, so that the current flowing through it increases with a slope fixed by the operating conditions. When the sensed current (a part of the high side current) reaches the output value of the error amplifier E/A, COMP pin, the internal logic turns off the high side MOSFET and turns on the low side one until the next clock cycle begins or the current flowing through it goes down to zero (ZERO CROSSING comparator). During the load transients, the voltage control loop keeps the output voltage in regulation changing the COMP pin value, fixing a new turn off threshold. Moreover, during these dynamic conditions the choke must not saturate and the inductor peak current must never exceed the maximum value. This value is function of the internal slope compensation (see related section).

4.1 MODES OF OPERATION

4.1.1 Low Consumption Mode

At light load, the device operates in burst mode in order to keep the efficiency very high also in these conditions. While the device is not switching the load discharges the output capacitor and the output voltage goes down. The COMP pin, due to the feedback loop, increases and when a fixed internal threshold is reached, the device starts to switch again. In this condition the peak current limit is set approximately in the range of 200mA-400mA, depending on the slope compensation (see related section). Once the device starts to switch the output capacitor is recharged. The repetition time of the bursts depend on parameters like input and output voltages, load, inductor and output capacitors.

Between two bursts, most of the internal circuitries are off, so reducing the device consumption down to a typical value of 25μ A. During the burst, the frequency of the pulses is equal to the internal frequency.

4.1.2 Low Noise Mode

In case the very low frequencies generated by the low consumption mode are undesirable, the low noise mode can be selected. The efficiency is a little bit lower compared with the low consumption mode conditions when working close to zero loads, while the trend is to reach the efficiency of low consumption mode for intermediate light loads.

The device could skip some cycles in order to keep the output voltage in regulation. In the figures 6 and 7 the LCM and LNM typical waveforms are shown.



Figure 6. Low Consumption mode

Figure 7. Low noise mode



Measurement conditions: $V_{IN} = 4.2V$; $V_{OUT} = 1.5V$; $I_{OUT} = 30$ mA; $L = 6.8\mu$ H; $C_{IN} = 10\mu$ F; $C_{OUT} = 22\mu$ F; $R_C = 40$ K Ω ; $C_C = 330$ pF

In figure 19 is shown a comparison between the efficiency in Low Noise Mode and the efficiency in Low Consumption Mode.

4.2 SYSTEM STABILITY

Since the device operates with constant frequency peak current mode architecture, the voltage loop stability is usually not a big issue. For most of the applications a 220pF connected between the COMP pin and ground is enough to guarantee the stability. In case very low ESR capacitors are used for the output filter, such as multilayer ceramic capacitors, the zero introduced by the capacitor itself can be shifted at a frequency well above the resonance frequency of the L-C filter and the loop stability could be affected. Adding a series resistor to the 220pF capacitor can solve this problem. The right value for the resistor can be determined by checking the load transient response voltage waveforms.

The current mode stability can be studied in two consecutive steps; first the inner loop is closed (current loop) and then the second loop stability is considered (voltage loop).

4.2.1 Current Loop Compensation

The selected control architecture brings many advantages: easy compensation with ceramic capacitors, fast transient response and intrinsic peak current measurement that simplify the current limit protection. A known drawback, however, is that the current loop becomes unstable, when the duty cycle exceeds 50%. This phenomenon is known as "sub-harmonic oscillation" and can be avoided by adding a slope compensation signal. Due to this fact, the current limit of the device decreases when the slope compensation signal is applied. The slope compensation is internally implemented from a duty around 30% and figure 8 shows how the slope compensation affects the device current limit.

Figure 8. Slope compensation

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The amount of slope compensation depends on the inductor current slope during the OFF time. This slope, for a given duty cycle, is inversely proportional to the inductor value. Since the device can be synchronized at higher frequency, it is reasonable to calculate the inductor value in terms of it. Finally, the input voltage affects the OFF time slope as well. This is obvious because, for a given duty cycle, the output voltage (and so the OFF time inductor current slope) is directly proportional to the input one. In order to better manage these issues, the amount of slope compensation does not depend only on the duty cycle but also on the switching frequency and the input voltage.

Table 2. Suggested inductor values for different switching frequencies, at V_{IN} = 3.6V and V_{OUT} = 1.8V.

F _{SW} [KHz]	Minimum inductor value [μ H]	
600	6.8	
1000	3.6	
1400	2.7	

Table 3. Suggested inductor values for different switching frequencies, at $V_{IN} = 5V$ and $V_{OUT} = 3.3V$.

F _{SW} [KHz]	Minimum inductor value [μ H]
600	8.2
1000	5.6
1400	3.6

In the above tables are indicated the minimum inductor values that ensure the current loop stability with an input voltage of 3.6Vand 5V. Also there is a maximum inductor value above which the loop can become unstable. For example, if the inductor is too high the LC double pole returns in bandwidth.

4.2.2 Voltage Loop Compensation

Ideally in a current mode control, after closing the current loop, the pole splitting effect separates the complex double pole due to the inductor and the output capacitor in 2 different poles; the pole due to the inductor shifts out of system bandwidth (i.e. the inductor ideally acts like a current source), while the pole due to the output capacitor remains inside the bandwidth. In figure 9 is shown the equivalent circuit used to study the voltage loop compensation:



Figure 9. Equivalent circuit for the voltage loop analysis

In the equation 1 the power stage transfer function is shown:

$$H(s) = \frac{V_O(s)}{I_1(s)} = \frac{(sC_OESR + 1)R_O}{sC_O(ESR + R_O) + 1}$$
Eq 1

where R_O is the output equivalent resistor load (V_O/I_O) and ESR is the series resistance of the output capacitors. It can be seen that the pole due to the output capacitor shifts in frequency based on the load value.

In order to have zero DC error in the voltage regulation, the feedback voltage loop is implemented with an integrator stage; the transfer function of the signal stage is shown in the equation 2.

$$G(s) = \frac{g_m \alpha sC_C R_C + 1}{sC_C}$$
Eq 2

Where g_m is the integrator transconductance (250µS). The total gain loop is:

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$$G_{LOOP}(s) = \frac{R_{O}g_{m}\alpha(1 + sESRC_{O})(sC_{C}R_{C} + 1)}{A_{V}sC_{C}(1 + sC_{O}(ESR + R_{O}))}$$
Eq 3

where A_V is the current loop factor (1 Ω typ.) and α is the feedback resistor divider ratio ($R_2/(R_2+R_3)$). Once the gain loop is known the system will be stabilized with the compensation network as shown in the 5.1.4 paragraph.

4.3 SHORT CIRCUIT PROTECTION

The device is provided by two limiting current circuitries, one on the high side and a second on the low side MOSFET.

Due to the peak current mode architecture, the peak current flowing through the high side switch is accurately sensed. When this current reaches the peak current limit threshold, the internal high side MOSFET is turned off. In this way, the ON time, T_{ON} , is reduced and the output voltage decreases. The minimum TON can be around 200nsec (T_{MIN}). In case of short circuit, the peak current could further increase because the intervention of the high side limiting current is not fast enough. In this case, the valley current limits eliminate the risks of device failure. To better understand this concept, it's useful to read the below considerations on the current variation through the inductor during the ON and OFF time.

$$\Delta I_{ON} = \frac{(V_{IN} - V_{OUT})}{L} \cdot T_{ON}$$
 (ON time slope) Eq 4

$$\Delta I_{OFF} = \frac{V_{OUT}}{L} \cdot T_{OFF} \text{ (OFF time slope)}$$
 Eq 5

When $V_{OUT} = 0V$, it can be seen that the inductor current doesn't decrease during the OFF time. Therefore the current will increase step by step during each cycle In order to understand when this phenomenon will end, some real parameter must be considered.

Figure 10. Equivalent circuits during the ON time



Figure 11. Equivalent circuit during the OFF time



Considering the figures above, in particular during the OFF time, in despite of the output voltage is zero, the output current generates, on the parasitic resistances, the voltage drop necessary to produce a negative slope. So, the higher will be the output current, the higher will be the negative slope during the OFF time; in this way, the inductor current will find a stable value. This value is given by:

$$I_{LIM} = \frac{V_{IN} \cdot (T_{MIN} \cdot F_{SW})}{[(R_N + R_L) \cdot (1 - T_{MIN} \cdot F_{SW}) + (R_P + R_L) \cdot (T_{MIN} \cdot F_{SW})]}$$
Eq 6

where T_{MIN} is the minimum ON time, F_{SW} is the switching frequency, R_N and R_P are the ON resistance of the low side and high side MOSFETs respectively, R_L is the inductor series resistance and R_O is the equivalent output resistance. As it can be seen, in these extreme conditions, the maximum current value depends both on the application conditions (like V_{IN} and F_{SW}), the inductor parasitic resistor R_L , and the MOSFETS RDS_{ON} R_N and R_P . It does not depend on the peak current limit at all. In order to limit the output current to a safe value even in extreme short circuit conditions, a current limit has also been introduced on the low side MOSFET: this operates as a valley current limit, as shown in figure 12. The high side MOS-FET does not turn-on until the inductor current exceeds the valley current limit. This implies that, depending on the over current conditions, the device skips some cycles, so reducing the equivalent switching frequency in order to limit the output current. With this approach, the maximum peak current is definitively limited to:

$$I_{LIM} = I_{VALLEY} + \frac{V_{IN}T_{MIN}}{L}$$
 Eq 7



Figure 12. Valley current limit protection

4.4 SYNCHRONIZATION

The device can be synchronized with an external signal from 500 KHz up to 1.4MHz through the internal PLL. When the device is locked, the external signal and the high side turn on rising edges are aligned. In this case the low noise mode is automatically selected. The device will eventually skip some cycles in very light load conditions depending also on the input/output conditions. The internal synchronization circuit is inhibited in short circuit and over voltage conditions in order to keep the involved protections effective. The synchronization signal amplitude can range typically from 1V to V_{CC} and the duty factor can range typically from 20% to 80%. Sometimes, if the synchronization signal duty cycle is very similar to the application duty factor, noise can be detected on the LX pin. In this case some practical solutions are:

- 1. Change the synchronization signal duty factor.
- 2. Decrease the synchronization signal amplitude.
- 3. Add 20pF capacitor between the Comp pin and ground.

The device switches at 600 KHz (typ.) if no synchronization signal is applied.

4.5 DROPOUT OPERATION

When the input voltage is a Li-Ion battery, the voltage ranges from a minimum of 3V or less to 4.1V-4.2V (depending on the anode material). In case the regulated output voltage is from 2.5V and 3.3V, the device can work in linear mode or dropout operation. The minimum input voltage necessary to ensure output reg-

ulation can be calculated as:

$$V_{IN_MIN} = V_O + I_O \cdot (R_{DSON_HS_MAX} + R_L)$$
 Eq 8

where RDS_{ON_HS_MAX} is the maximum high side resistance and RL is the series inductor resistance.

4.6 PGOOD (Power Good Output)

The pin is an open drain output and so, a pull up resistor should be connected to it. If the feature is not required, the pin can be left floating. A power good signal, low, is available, until the output voltage reaches the 90% of the final value. After that, the PGOOD signal goes high and the internal transistor goes off.

4.7 ADJUSTABLE OUTPUT VOLTAGE

The output voltage can be adjusted by an external resistor network from a minimum value of 0.6V up to the V_{IN} . The output voltage value is given by:

$$V_{OUT} = 0.6 \cdot \left(1 + \frac{R_3}{R_2} \right)$$
 Eq 9

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Thanks to the very low FB leakage current (typ. 25nA), high R3, R2 values can be chosen of hundreds of $K\Omega$ increasing the system efficiency also at very low load.

4.8 OVP (Over voltage Protection)

The device has an internal output over voltage protection. If the output voltage goes higher than 10% of its nominal value, the low side MOSFET is turned on until the output voltage returns inside the nominal value tolerances. During the over voltage circuit intervention, the zero crossing comparator is disabled so that the device is also able to sink current.

4.9 HYSTERETIC THERMAL SHUTDOWN

The device has also a thermal shutdown protection activated when the junction temperature goes above 150°C. In this case both the high side MOSFET and the low side one are turned off. Once the junction temperature goes back to about 95°C, the device restarts the normal operation.

5 APPLICATION INFORMATIONS

5.1 EXTERNAL COMPONENTS SELECTION

5.1.1 Input Capacitor

The input capacitor must be able to support the maximum input operating voltage and the maximum RMS input current. Since step-down converters draw current from the input in pulses, the input current is squared and the height of each pulse is equal to the output current, neglecting the ripple across the inductor. The RMS input current (flowing through the input capacitor) is:

$$I_{RMS} = I_{O} \cdot \sqrt{D - \frac{2 \cdot D^{2}}{\eta} + \frac{D^{2}}{\eta^{2}}}$$
 Eq 10

Where η is the expected system efficiency, D is the duty cycle and Io the output DC current. Supposing η =1 this function reaches its maximum value at D=0.5 and the equivalent RMS current is equal to Io/2. The maximum and minimum duty cycles are:

$$D_{MAX} = \frac{V_{O}}{V_{INMIN}}$$
 Eq 11

$$D_{MIN} = \frac{V_{O}}{V_{INMAX}}$$
 Eq 12

Depending on the output voltage value the worst case can be with the maximum or minimum input battery voltage. In principle different types of capacitor can be considered (tantalum, electrolytic, ceramics...) but for battery powered applications the best choice are the multiplayer ceramic caps due to their very small size and ESR. Below there is a list of some multiplayer ceramic capacitors (MLCC) manufacturer.

Table 4. Recommended input capacitors.

Manufacturer	Series	Cap Value (μF)	Rated Voltage (V)	ESR @600KHz (mΩ)
PANASONIC	ECJ	10 to 22	6.3	10
TAIYO YUDEN	JMK	10 to 22	6.3	10

5.1.2 Output Capacitor

The output capacitor is very important to satisfy the output voltage ripple requirement. Very small inductors values reduce size and cost of the application but increase the current ripple. This ripple, multiplied by the ESR of the output capacitor is the output voltage ripple. Tantalum and ceramic capacitors are usually good for this use. Ceramic capacitors have the lowest ESR for a given size so, for very compact applications they are the best choice. POSCAP capacitors from Sanyo are also a good choice for the output filter. Below, there is a list of some capacitors manufacturer.

Table 5. Recommended output capacitors.

Manufacturer	Series	Cap Value (μF)	Rated Voltage (V)	ESR (mΩ)
PANASONIC	ECJ	10 to 47	6.3	10
PANASONIC	EEF	22 to 47	6.3	60 to 90
TAIYO YUDEN	JMK	10 to 47	6.3	10
SANYO POSCAP	TPA	47 to 100	6.3	80 to 100

5.1.3 Inductor

The inductor value fixes the ripple current flowing through the output capacitor. The ripple current is usually fixed at 20%-30% of the output current and is approximately obtained by the following formula:

$$L = \frac{(V_{IN} - V_{OUT})}{\Delta I} \cdot T_{ON}$$
 Eq 13

For example, with $V_{OUT} = 3.3V$, $V_{IN} = 4.2V$ (Li-ion battery fully charged), $F_{SW} = 600$ KHz and $I_O = 600$ mA and $\Delta I = 200$ mA, the inductor value is about 6uH. The peak current through the inductor is given by:

$$I_{PK} = I_{O} + \frac{\Delta I}{2}$$
 Eq 14

It can be seen that if the inductor value decreases, the peak current (that has to be lower than the current limit of the device) increases. This peak current must be lower than the saturation current of the choke. This is particularly important when using ferrites core because they can hardly saturate (the inductance value decreases abruptly when the saturation threshold is exceeded so causing an abrupt increase of the current flowing through it). The inductor should be selected also considering the system stability, (see the slope compensation paragraph). Moreover the inductor selection should be made taking in account the inductor parasitic resistance, because a too high value can decrease the efficiency. In the following table some inductor manufacturers are listed.

Manufacturer	Series	Inductor Value (μ H)	Saturation Current (A)
Coilcraft	DO1607C	6.8 to 15	0.72 to 0.96
	DT1608C	6.8 to 15	0.6 to 1
	LPO1704	6.8 to 10	0.8 to 0.9
	DO1606T	6.8 to 10	1 to 1.1
Panasonic	ELL6RH	6.2 to 22	0.7 to 1.4
	ELL6GM	6.8 to 10	0.93 to 1.1
Toko	D62CB	10 to 22	0.71 to 1.07
	D62C	10 to 22	0.63 to 0.99

Table 6. Recommended inductors.

5.1.4 Compensation network (R1C3)

As it is shown in the paragraph 4.2 the system stability can be studied with the loop transfer function given by the eq3. If the output capacitor is a ceramic type the zero due to the ESR generally will be out of the system bandwidth, so the stability of the system will be ensured by the cancellation between the pole due to the output capacitor and the equivalent load and the R_1C_3 zero. In the equation 15, a simplified gain loop expression, valid around the transition frequency f_T is given by:

$$G_{LOOP}(s) = \frac{g_m R_1 \alpha}{s C_2}$$
 Eq 15

Supposing $C_2 = 22\mu$ F, the transition frequency at 0dB equal to 30 KHz (fT is equal to the system bandwidth), and the output voltage equal to 1.8V the R₁ value can be calculated as:

$$R_{1} = \frac{2\pi f_{T}C_{2}}{g_{m}\alpha} = 48k\Omega$$
 Eq 16



The nearest standard E12 series value is $R_1 = 47 K\Omega$.

The higher is the bandwidth, the faster will be the transient response but the bandwidth (and so the R_1 value) must be lower than f_{SW}/10 to avoid the effect due to the sampling effect poles as mentioned in the 4.2 paragraph. The zero due to the compensation network must be at the least 5 times before the frequency transition, so the C₃ value will be:

$$C_3 = \frac{5}{2\pi f_T R_1} = 500 pF$$
 Eq 17

The nearest standard value is $C_3 = 470 pF$

If the output capacitors are tantalum type the ESR zero is in the system bandwidth and it can be used to stabilize the system so the zero due to the compensation network will be useless (the C_3 is necessary to the integrator function).

5.2 LOSSES and EFFICIENCY

There are losses affecting the efficiency of the application. Some of these losses are related to the device and others are related to the external components. The most important losses are listed below.

5.2.1 Conduction Losses.

These losses are basically due to the not negligible resistances of the internal switches and the external inductor. Usually the current ripple across the inductor is negligible and so to estimate the conduction losses of the inductor, the average output current can be considered. The conduction losses of the switches depend also on the duty cycle of the application. The RMS current flowing through the high side MOSFET is $(I_0)^2 \cdot D$ while the RMS current flowing through the low side MOSFET is $(I_0)^2 \cdot (1-D)$. So, the total conduction losses are:

$$P_{MOS} = I_0^2 \cdot (R_P \cdot (D) + R_N \cdot (1 - D) + R_L)$$
 Eq 18

where R_P and R_N are the series resistance of the high side and low side MOSFETs respectively and R_L the series resistance of the inductor. The conduction losses due to the ESR of the input and output capacitors are usually negligible, particularly when using ceramic caps (very low ESR). Anyway, in case of high ESR values for these caps, their conduction losses are:

$$P_{CIN, COUT} = I_{O}^{2} \cdot (D \cdot (1 - D)) \cdot ESR_{CIN} + \frac{\Delta I^{2}}{12} \cdot ESR_{COUT}$$
 Eq 19

where ΔI is the current ripple flowing through the choke and D is the duty cycle of the application. The conduction losses are particularly important at high current cause they depends on its squared value.

5.2.2 Switching Losses.

The switching losses are due to the turn on and off of the internal high side MOSFET.

$$P_{SWITCHING} = V_{IN} \cdot I_O \cdot F_{SW} \cdot \frac{(T_{ON} + T_{OFF})}{2}$$
 Eq 20

where T_{ON} and T_{OFF} are the turn-on and turn-off times of the internal high side switch. These are approximately in the range of 15ns to 20ns. This loss is important at high frequency.

5.2.3 Gate Charge Losses

The gate charge losses derive from switching the gate capacitance of the internal MOSFETs. The gate capacitances (CH for the high side MOSFETs and CL for the low side MOSFETs) are charged and discharged with the input voltage at the switching frequency.

$$P_{GATE_CHARGE} = V_{IN} \cdot (C_{H} + C_{L}) \cdot F_{SW}$$
 Eq 21

These losses are also directly proportional to the switching frequency and input voltage but are usually negligible compared with the conduction and switching losses.

5.3 THERMAL CONSIDERATIONS

Depending on the electrical application conditions (input voltage, switching frequency, and output current) and ambient temperature, the heat produced by device losses could increases the junction temperature over its absolute maximum rating. The following relation can estimate the junction temperature of the device:

$$T_J = T_A + R_{TH JA} \cdot P_{TOT}$$
 Eq 22

where T_A is the ambient temperature of the application, R_{TH_JA} is the thermal resistance junction to ambient of the package and P_{TOT} is the overall power dissipated by the device. R_{TH_JA} depends a little bit on the application board but it can approximately considered equal to 180 C/W. P_{TOT} is given by:

$$P_{TOT} = P_{MOS} + P_{SWITCHING} + P_{GATE_CHARGE}$$
 Eq 23

Figure 13. Thermal Performance results: VIN = 3.7V VOUT = 1.8V IOUT = 800mA



Figure 14. RDSON Vs temperature



For a better estimation of the power dissipated it can be useful to consider the MOSFETs RDSON variation with the temperature, shown in the figure 14.

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5.3.1 APPLICATION BOARD

5.3.1.1 Demoboard layout

In the figures below the demo board layout is shown.

Figure 15. Component placement



Figure 16. Top side view



Figure 17. Bottom side view



5.3.1.2 Demo board schematic

The very small package and high switching frequency allows a very compact application. The demo board circuit is shown in Fig.18:





Table 7. Demo board part list.

Reference	Part Number	Description	Manufacturer
C1	ECJ3XBOJ106K	10μF 6.3V	Panasonic
C2	ECJ4XBOJ226M	22μF 6.3V	Panasonic
C3	C0406C221J5GAC	220pF, 5% 50V	Kemet
R1		10K 1% 0402	Neohm
R2		100K 1% 0402	Neohm
R3		450K 1% 0402	Neohm
R4		100K 1% 0402	Neohm
L1	ELL6GM100M	10μH 0.9A	Panasonic

Figure 19. Low noises Vs Low consumption efficiencies



5.4 EFFICIENCY RESULTS

Some efficiency results are shown below.

Figure 20. Efficiency vs Output Current



Figure 21. Efficiency vs Output Current



Figure 22. Efficiency vs Output Current

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6 APPLICATION IDEAS

6.1 BUCK BOOST TOPOLOGY

In portable applications, the input voltage changes a lot due to the battery discharge profile that often depends on many parameters like temperature, discharge rate, battery ageing, etc... Moreover, in particular applications, the output voltage requirements can also change. This could imply that is not possible to provide the desired regulated output voltage by using the simple buck topology. This problem is often present, for example, in systems using a single Li-Ion cell, whose voltage profile changes from 4.2V down to 2.7V or less. In fact, in these systems, a 3.3V output is normally required to power processor I/O, memory and logic. Adopting the buck topology, the 3.3V output can be regulated until the battery voltage is approximately 3.4V, also depending on the minimum dropout of the regulator. Depending on the battery type and conditions, this would leave unused some 20%-30% of its capacity. Another application, even more critical, is the power management of 3G phones, where a 3.7V or more can be required to power the RF Power Amplifier (PA).

In order to use the full battery capacity also in these applications, a positive buck_boost topology can be used. Figure 22 shows how to implement it. This topology can be more suitable, compared to a standard buck, depending on the battery discharge profile and the load conditions. In fact, the efficiency loss of the buck-boost topology can be translated into an equivalent loss in battery capacity. This can then be compared with the gain in battery capacity due to the fact that it is used over the full voltage range.



Figure 23. Positive Buck Boost Application. 1 Li-Ion cell to 3.3V@0.25A

6.2 WHITE LED

White LEDs are now widely used both for LCD backlighting and for illumination. Since their brightness is proportional to the current flowing through them, a current control loop must be implemented instead of a voltage one. The device can be used in current control architecture by simply inserting a sense resistor between the FB and GND pins and connecting the LED in series with it. The loop will set 0.6V across the sense resistor, and so, a constant current flowing through the LED. The current, and by consequence, the brightness, can be adjusted by changing the resistor value or the voltage across it (by partitioning the FB pin voltage). The forward voltage across a white LED is approximately 3.6V and so, depending on the input source, appropriate topologies must be used.

6.2.1 Driving White LEDs: Buck Topology

The simple buck topology can be used when the input voltage source is higher than approximately 4.5V that is the case, for example, with the USB bus.

Figure 24. Buck topology schematic



In this case, the maximum device current (800mA, continuous) can be delivered to the LED. Moreover, in this topology, the efficiency is maximized.

6.2.2 Driving White LEDs: Boost Topology

When the input voltage source is always lower than 3V (that is the case, for example, of 2 cells of NiMH battery) a boost topology must be implemented, as shown in figure 24.



Figure 25. Boost topology schematic

In this case, according to the boost topology, the maximum current that can be delivered depends on the duty cycle. The relation between the output current and the internal switch current (assuming a negligible current ripple and 100% efficiency) is given in equation 24:

$$I_{OUT} = IS_{WITCH} (1-D)$$
 Eq 24

This topology is possible because the input source is a battery, and so it must not be referred to ground. A drawback of this approach, intrinsic in the boost topology, is that a path between the input and output is always present. This does not allow an effective short circuit protection and can generate a battery discharge also when the device is turned off.

6.2.3 Driving White LEDs: Buck_Boost Topology

In case a single Li-Ion cell is used at the input, a buck-boost topology can be used, as shown in figure 25.





The relation from the output current and the switch current is the same as the boost topology. An advantage of this topology compared with the boost one, is that when the device is turned off, there is no current path between the input and the output. This allows an effective short circuit protection and minimizes the current drawn from the battery when the device is turned off.

A dimming control can be developed by turning on and off the device with a frequency around 100-200Hz in order to avoid led flickering. Another way to implement the led dimming is to reduce the voltage drop across the resistor in series to the LED to a partition of the FB voltage. The figures 27 and 28 shows the relative circuits



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Figure 27. PWM brightness control

Figure 28. Analog brightness control



Both of solutions change the output current by changing then FB voltage. In the figure 26 is used a DC voltage; instead in the figure 27 is used the average voltage coming from the PWM signal.

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